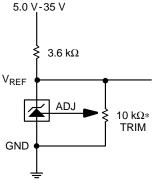
2.5 Volt Reference

The NCV1009 is a precision trimmed 2.5 V ± 5.0 mV shunt regulator diode. The low dynamic impedance and wide operating current range enhances its versatility. The tight reference tolerance is achieved by on-chip trimming which minimizes voltage tolerance and temperature drift.

A third terminal allows the reference voltage to be adjusted $\pm 5.0\%$ to calibrate out system errors. In many applications, the NCV1009Z can be used as a pin-to-pin replacement of the LT1009CZ and the LM136Z-2.5 with the external trim network eliminated.

Features

- 0.2% Initial Tolerance Max.
- Guaranteed Temperature Stability
- Maximum 0.6 Ω Dynamic Impedance
- Wide Operating Current Range
- Directly Interchangeable with LT1009 and LM136 for Improved Performance
- No Adjustments Needed for Minimum Temperature Coefficient
- Meets Mil Std 883C ESD Requirements
- Extended Operating Temperature Range for Use in Automotive Applications
- NCV Prefix, for Automotive and Other Applications Requiring Site and Change Control



*±5.0% Trim Range

If the external trim resistor is not used, the "ADJ. PIN" should be left floating. The 10k trim potentiometer does not effect the temperature coefficient of the device.

Figure 1. Application Diagram



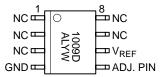
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SO-8 D SUFFIX CASE 751

PIN CONNECTIONS AND MARKING DIAGRAM



A = Assembly Location

WL, L = Wafer Lot YY, Y = Year WW, W = Work Week

ORDERING INFORMATION

Device	Package	Shipping
NCV1009D	SO-8	95 Units/Rail
NCV1009DR2	SO-8	2500 Tape & Reel

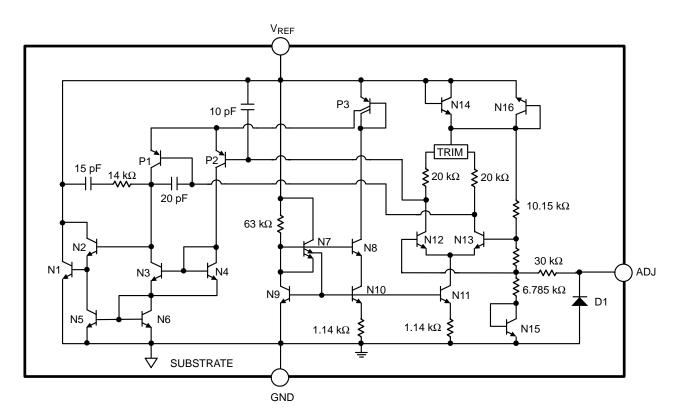


Figure 2. Block Diagram

MAXIMUM RATINGS*

Rating	Value	Unit
Reverse Current	20	mA
Forward	10	mA
Package Thermal Resistance, SO-8: Junction-to-Case, $R_{\theta JC}$ Junction-to-Ambient, $R_{\theta JA}$	45 165	°C/W
Operating Temperature Range	-40 to +125	°C
Storage Temperature Range	-65 to +150	°C
, ,	ough hole styles only) (Note 1) 260 peak (SMD styles only) (Notes 2, 3) 240 peak	°C °C

- 1. 10 second maximum
- 60 second maximum above 183°C.
- 3. -5°C / +0°C allowable conditions.

ELECTRICAL CHARACTERISTICS $(T_A = 25^{\circ}C)$ unless otherwise specified.)

Characteristic	Test Conditions		Min	Тур	Max	Unit
Reverse Breakdown Voltage	I _R = 1.0 mA		2.492	2.500	2.508	V
Reverse Breakdown Voltage	$0^{\circ}C \leq T_{A} \leq 125^{\circ}C$		2.492	2.500	2.508	V
Reverse Breakdown Voltage	$-40^{\circ}C \le T_A \le 0^{\circ}C$		2.480	2.500	2.508	V
Reverse Breakdown Voltage Change with Current	$400 \ \mu\text{A} \le I_R \le 10 \ \text{mA}$	t	-	2.6 3.0	5.0 6.0	mV mV
Reverse Dynamic Impedance	I _R = 1.0 mA	t	-	0.2 0.4	1.0 1.4	Ω Ω
Temperature Stability Average Temperature Coefficient	$0^{\circ}C \le T_A \le 70^{\circ}C$, Note 4 $0^{\circ}C \le T_A \le 70^{\circ}C$, Note 4			1.8 15		mV ppm/°C
Long Term Stabilty	$T_A = 25^{\circ}C \pm 0.1 \text{ C}, I_R = 1.0 \text{ mA}$		-	20	-	ppm/kHr

- † Denotes the specifications which apply over full operating temperature range.4. Average temperature coefficient is defined as the total voltage change divided by the specified temperature range.

TYPICAL PERFORMANCE CHARACTERISTICS

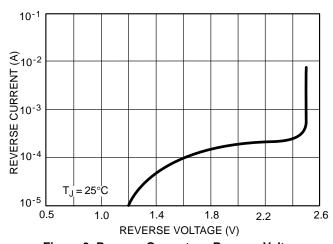


Figure 3. Reverse Current vs. Reverse Voltage

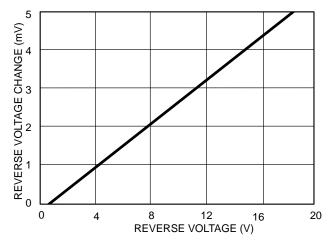
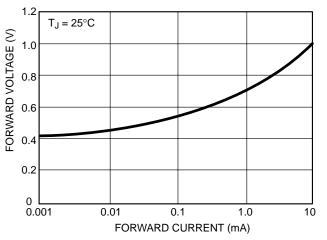


Figure 4. Change in Reverse Voltage vs. **Reverse Current**

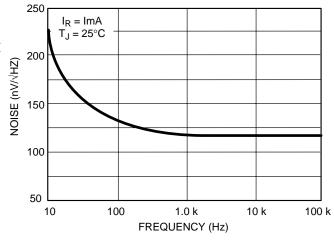
^{*}The maximum package power dissipation must be observed.



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Figure 5. Forward Voltage vs. Forward Current

Figure 6. Dynamic Impedance vs. Frequency



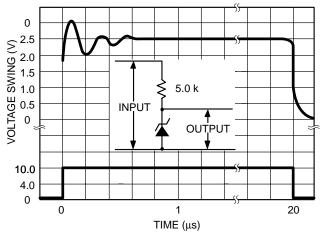
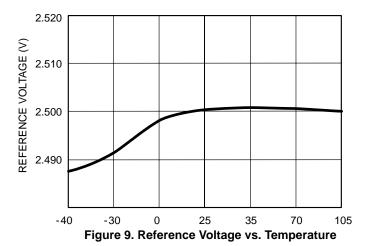


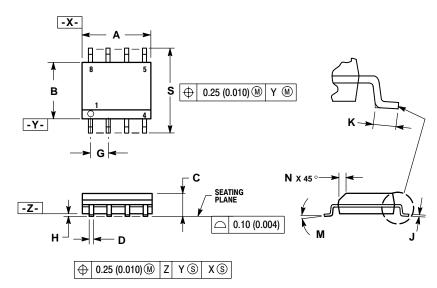
Figure 7. Zener Noise Voltage vs. Frequency

Figure 8. Response Time



PACKAGE DIMENSIONS

SO-8 **D SUFFIX** CASE 751-07 **ISSUE AA**



- NOTES:

 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

 2. CONTROLLING DIMENSION: MILLIMETER.

 3. DIMENSION A AND B DO NOT INCLUDE MOLD PROTRUSION.

 4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.

 5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.

 6. 751-01 THRU 751-06 ARE OBSOLETE. NEW STANDARD IS 751-07

	MILLIN	IETERS	INCHES		
DIM	MIN	MAX	MIN	MAX	
Α	4.80	5.00	0.189	0.197	
В	3.80	4.00	0.150	0.157	
С	1.35	1.75	0.053	0.069	
D	0.33	0.51	0.013	0.020	
G	1.27 BSC		0.050 BSC		
Н	0.10	0.25	0.004	0.010	
J	0.19	0.25	0.007	0.010	
K	0.40	1.27	0.016	0.050	
M	0 °	8 °	0 °	8 °	
N	0.25	0.50	0.010	0.020	
S	5.80	6.20	0.228	0.244	

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